

Low Dropout Voltage Tracking Regulator

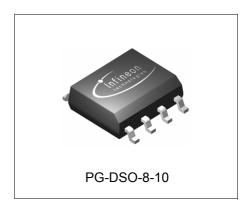
TLE 4254





Feature Overview

- 70 mA output current capability
- · Tight output tracking tolerance to reference
- Output voltage adjustable down to 2.0 V
- Stable operation with 1 µF ceramic output capacitor
- Flexibility of output voltage adjust higher or lower than reference, proportional to the reference voltage (version GA)
- Status output to indicate short circuits at the output (version GS)
- Very low dropout voltage of typ. 0.2 V @ maximum output current
- · Combined reference / enable input
- Very low current consumption in OFF mode
- Wide input voltage range -20 V ≤ V₁ ≤ +45 V
- Wide temperature range: -40 °C ≤ T_i ≤ 150 °C
- · Output protected against short circuit to GND and battery
- Input protected against reverse polarity
- Overtemperature protection
- Green product (RoHS compliant)
- AEC qualified



Functional Description

The TLE 4254 is a monolithic integrated low-dropout voltage tracking regulator in a small PG-DSO-8 package. The IC is designed to supply off-board systems, e. g. sensors in powertrain management systems under the severe conditions of automotive applications. Therefore, the IC is equipped with additional protection functions against reverese polarity and short circuit to GND and battery.

With supply voltages up to 40 V, the output voltage follows a reference voltage applied at the adjust input with very high accuracy. The reference voltage applied directly to the adjust input or by an e. g. external resistor divider can be 2.0 V at minimum.

The output is able to drive loads up to 70 mA while the device follows with high accuracy the e. g. 5 V output of a main voltage regulator acting as reference.

The TLE 4254 can be set into shutdown mode in order to reduce the current consumption to a minimum. This suits the IC for low power battery applications.

Version "GS" offers an open collector status output indicating an overvoltage and undervoltage error condition of the output voltage.

Version "GA" allows setting the output voltage to higher value than the reference voltage by connecting a voltage divider to the feedback pin "FB".

Туре	Package
TLE 4254 GA	PG-DSO-8-10 (RoHS compliant)
TLE 4254 GS	PG-DSO-8-10 (RoHS compliant)

Data Sheet 1 Rev. 1.0, 2006-11-22



Pin Definitions and Functions

1 Pin Definitions and Functions

1.1 Pin Assignment

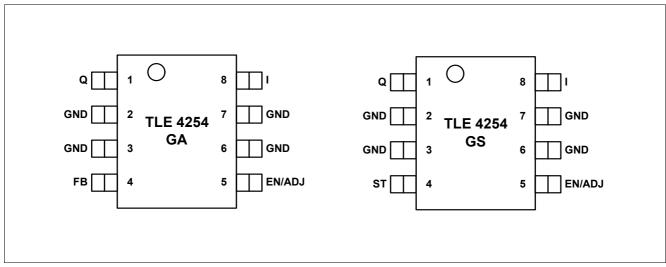


Figure 1 Pin Configurations

1.2 Pin Functions

Pin	Symbol	Function
1	Q	Tracker Output. Block to GND with a capacitor close to the IC terminals, respecting capacitance and ESR requirements given in the table "Functional Range".
2, 3, 6, 7	GND	Ground reference. Interconnect the pins on PCB. Connect to heatsink area.
4	FB (version GA)	Feedback input (version GA only). Non inverting input of the internal error amplifier to control the output voltage. Connect this pin directly to the output pin in order to obtain lower or equal output voltages with respect to the reference voltage. Connect a voltage divider for higher output voltages than the reference. (See also application information.)
4	ST (version GS)	Tracking Regulator Status Output (version GS only). Open collector output. Connect via a pull-up resistor to a positive voltage rail. A low signal indicates fault condions at the regulator's output.
5	EN/ADJ	Adjust / Enable. Connect the reference to this pin. The active high signal of the reference turns on the device; a low signal disables the IC. The reference voltage can be connected directly or by a voltage divider for lower output voltages (see application information).
8	1	Input. IC supply. For compensating line influences, a capacitor close to the IC terminals is recommended.



General Product Characteristics

2 General Product Characteristics

2.1 Absolute Maximum Ratings

Absolute Maximum Ratings 1)

-40 °C $\leq T_{\rm j} \leq$ 150 °C; all voltages with respect to ground (unless otherwise specified). Not subject to production test; specified by design.

Pos.	Parameter	Symbol	Limit Values		Unit	Conditions
			Min.	Max.		
Voltage	es			'	-	
2.1.1	Input voltage	V_1	-20	45	V	_
2.1.2	Adjust / Enable input voltage	$V_{ADJ/EN}$	-20	45	V	_
2.1.3	Output voltage	V_{Q}	-5	45	V	_
2.1.4	Feedback input voltage (version GA)	V_{FB}	-20	45	V	_
2.1.5	Status output voltage (version GS)	V_{ST}	-0.3	7	V	_
Tempe	ratures			'	-	
2.1.6	Junction Temperature	$T_{\rm j}$	-40	150	°C	_
2.1.7	Storage Temperature	$T_{\rm stg}$	-50	150	°C	_
ESD Ra	ating				l.	
2.1.8	ESD Susceptibility	$V_{\rm ESD,HBM}$	4	_	kV	HBM ²⁾
2.1.9		$V_{ESD,CDM}$	1	_	kV	CDM 3)

¹⁾ Not subject to production test, specified by design.

Note: Stresses above the ones listed here may cause permanent damage to the device. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

Note: Integrated protection functions are designed to prevent IC destruction under fault conditions described in the data sheet. Fault conditions are considered as "outside" normal operating range. Protection functions are not designed for continuous repetitive operation.

²⁾ ESD susceptibility Human Body Model "HBM" according to EIA/JESD 22-A 114B

³⁾ ESD susceptibility Charged Device Model "CDM" according to EIA/JESD22-C101 or ESDA STM5.3.1



General Product Characteristics

2.2 Functional Range

Pos.	Parameter	Symbol	Lim	it Values	Unit	Conditions
			Min.	Max.		
2.2.1	Input Voltage	V_{l}	4	45	V	$V_{I} \ge V_{Q} + V_{dr}$
2.2.1	Adjust / Enable Input Voltage (Voltage Tracking Range)	$V_{ m ADJ/EN}$	2.0	_	V	-
2.2.2	Junction Temperature	T_{i}	-40	150	°C	_
2.2.3	Output Capacitor	C_{Q}	1	_	μF	_ 1)
2.2.4		ESR _{CQ}	_	5	Ω	_ 1)

¹⁾ Not subject to production test; specified by design.

Note: Within the functional range the IC operates as described in the circuit description. The electrical characteristics are specified within the conditions given in the related electrical characteristics table.

2.3 Thermal Resistance

Pos.	Parameter	Symbol	Typ. Value	Unit	Conditions
PG-DS0	D-8-10:				
2.3.1	Junction – Ambient	$R_{th,j-a}$	155	K/W	Footprint only 1) 2)
2.3.2			96	K/W	300 mm ² PCB heatsink area 1) 2)
2.3.3			86	K/W	600 mm ² PCB heatsink area ^{1) 2)}

¹⁾ Package mounted on PCB FR4; 80 x 80 x 1.5 mm; 35 µm Cu, 5 µm Sn; horizontal position; zero airflow.

²⁾ Not subject to production test; specified by design.



3 Electrical Characteristics

3.1 Tracking Regulator

The output voltage $V_{\rm Q}$ is controlled by comparing it to the voltage applied at pin ADJ/EN and driving a PNP pass transistor accordingly. The control loop stability depends on the output capacitor $C_{\rm Q}$, the load current, the chip temperature and the poles/zeros introduced by the integrated circuit and the load. To ensure stable operation, the output capacitor's capacitance and its equivalent series resistor ESR requirements given in the table "Functional Range" have to be maintained. For details see also the typical performance graph "Output Capacitor Series Resistor $ESR_{\rm CQ}$ vs. Output Current $I_{\rm Q}$ ". Also, the output capacitor shall be sized to buffer load transients.

An input capacitor $C_{\rm I}$ is strongly recommended to buffer line influences. Connect the capacitors close to the IC terminals.

Protection circuitry prevent the IC as well as the application from destruction in case of catastrophic events. These safeguards contain output current limitation, reverse polarity protection as well as thermal shutdown in case of overtemperature.

In order to avoid excessive power dissipation that could never be handled by the pass element and the package, the maximum output current is decreased at high input voltages.

The overtemperature protection circuit prevents the IC from immediate destruction under fault conditions (e. g. output continuously short-circuited) by reducing the output current. A thermal balance below 200 °C junction temperature is established. Please note that a junction temperature above 150 °C is outside the maximum ratings and reduces the IC lifetime.

The TLE 4254 allows a negative supply voltage. However, several small currents are flowing into the IC increasing its junction temperature. This has to be considered for the thermal design, respecting that the thermal protection circuit is not operating during reverse polarity condition.

Table 1 Electrical Characteristics Tracking Regulator

 $V_{\rm I}$ = 13.5 V; $V_{\rm ADJ/EN}$ \geq 2.0 V; $V_{\rm FB}$ = $V_{\rm Q}$ (version GA); -40 °C \leq $T_{\rm j}$ \leq 150 °C; $C_{\rm Q}$ = 1 μ F; all voltages with respect to ground (unless otherwise specified).

Pos.	Parameter	Symbol	L	Limit Values			Test Condition
			Min.	Тур.	Max.		
3.1.1	Output Voltage Tracking Accuracy $\Delta V_{\rm Q} = V_{\rm EN/ADJ} - V_{\rm Q}$	ΔV_{Q}	-5	_	5	mV	$8 \text{ V} \leq V_{\text{I}} \leq 18 \text{ V};$ $0.1 \text{ mA} \leq I_{\text{Q}} \leq 60 \text{ mA};$ $V_{\text{ADJ/EN}} = 5 \text{ V}$
3.1.2			-10	_	10	mV	$5.5 \text{ V} \le V_{\text{I}} \le 26 \text{ V};$ $0.1 \text{ mA} \le I_{\text{Q}} \le 60 \text{ mA};$ $V_{\text{ADJ/EN}} = 5 \text{ V}$
3.1.3			-10	_	10	mV	5.5 V $\leq V_{\rm I} \leq$ 32 V; 0.1 mA $\leq I_{\rm Q} \leq$ 30 mA; $V_{\rm ADJ/EN}$ = 5 V
3.1.4	Load Regulation steady-state	$ \mathrm{d}V_{\mathrm{Q,load}} $	_	1	10	mV	$I_{\rm Q}$ = 0.1 mA to 70 mA; $V_{\rm ADJ/EN}$ = 5 V
3.1.5	Line Regulation steady-state	$ \mathrm{d}V_{\mathrm{Q,line}} $	_	1	10	mV	$V_{\rm I}$ = 5.5 V to 32 V; $I_{\rm Q}$ = 5 mA $V_{\rm ADJ/EN}$ = 5 V



Table 1 Electrical Characteristics Tracking Regulator

 $V_{\rm I}$ = 13.5 V; $V_{\rm ADJ/EN}$ \geq 2.0 V; $V_{\rm FB}$ = $V_{\rm Q}$ (version GA); -40 °C \leq $T_{\rm j}$ \leq 150 °C; $C_{\rm Q}$ = 1 μ F; all voltages with respect to ground (unless otherwise specified).

Pos.	Parameter	Symbol	L	imit Va	lues	Unit	Test Condition
			Min.	Тур.	Max.		
3.1.6	Power Supply Ripple Rejection	PSRR	60	_	-	dB	$f_{ m ripple}$ = 100 Hz; $V_{ m ripple}$ = 1 Vpp $I_{ m Q}$ = 5 mA $C_{ m Q}$ = 10 μ F, ceramic type ¹⁾
3.1.7	Dropout Voltage $V_{dr} = V_{l} - V_{Q}$	V_{dr}	_	200	400	mV	$I_{\rm Q}$ = 70 mA ²⁾
3.1.8	Output Current Limitation	$I_{Q,max}$	71	100	150	mA	$V_{\rm Q}$ = ($V_{\rm ADJ/EN}$ - 0.1 V); $V_{\rm ADJ/EN}$ = 5 V
3.1.9	Reverse Current	I_{Q}	-4	-2	_	mA	$V_1 = 0 \text{ V};$ $V_Q = 32 \text{ V};$ $V_{\text{ADJ/EN}} = 5 \text{ V}$
3.1.10	Reverse Current at Negative Input Voltage	I_{l}	-5	-3	_	mA	$V_{\rm I}$ = -16 V; $V_{\rm Q}$ = 0 V; $V_{\rm ADJ/EN}$ = 5 V
Feedba	ack Input FB (version GA only	y):			·		
3.1.11	Feedback Input Biasing Current	I_{FB}	_	0.1	0.5	μΑ	V_{FB} = 5 V
Overte	mperature Protection:						
3.1.12	Junction Temperature Equilibrium	$T_{ m j,eq}$	151	-	200	°C	$T_{\rm j}$ increasing due to power dissipation generated by the IC $^{1)}$

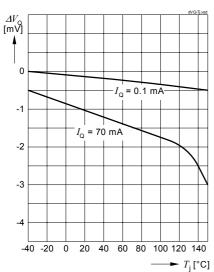
¹⁾ Parameter not subject to production test; specified by design.

²⁾ Measured when the output voltage $V_{\rm Q}$ has dropped 100 mV from its nominal value.

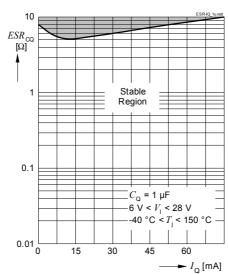


Typical Performance Characteristics Tracking Regulator

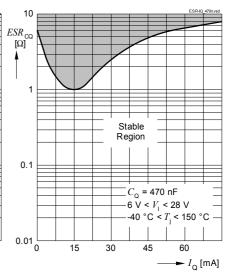
Tracking Accuracy $\Delta V_{\rm Q}$ vs. Junction Temperature T_i



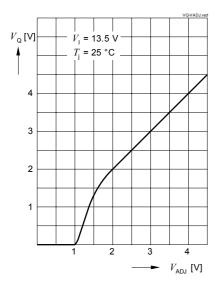
 $\textit{ESR}_{\texttt{CQ}}$ vs. Output Current $I_{\texttt{Q}}$



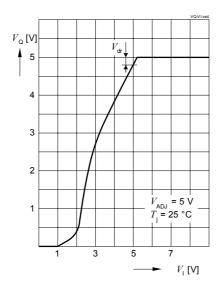
Output Capacitor Series Resistor Output Capacitor Series Resistor ESR_{CQ} vs. Output Current I_{Q}



Output Voltage $V_{\rm Q}$ vs. Adjust Voltage $V_{\mathrm{ADJ,EN}}$



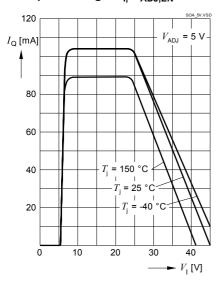
Output Voltage $V_{\rm Q}$ vs. Input Voltage V_1



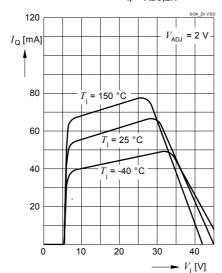


Typical Performance Characteristics Tracking Regulator

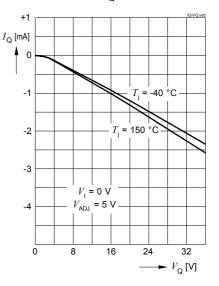
Output Current Limitation $I_{\rm Q,max}$ vs. Input Voltage $V_{\rm I,}$ $V_{\rm ADJ,EN}$ = 5V



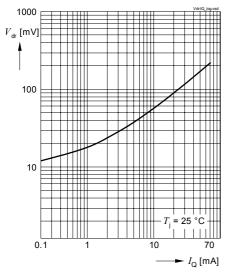
Output Current Limitation $I_{\rm Q,max}$ vs. Input Voltage $V_{\rm I}$, $V_{\rm ADJ,EN}$ = 2V



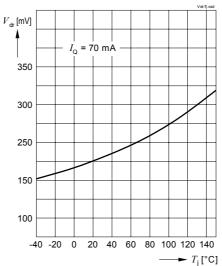
Reverse Output Current $I_{\rm Q}$ vs. Output Voltage $V_{\rm Q}$



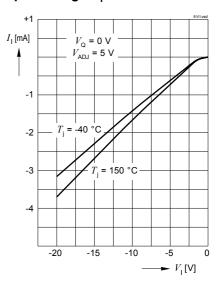
Dropout Voltage V_{dr} vs. Output Current I_{O}



Dropout Voltage $V_{
m dr}$ vs. Junction Temperature $T_{
m i}$



Reverse Current $I_{\rm I}$ vs. Input Voltage $V_{\rm I}$





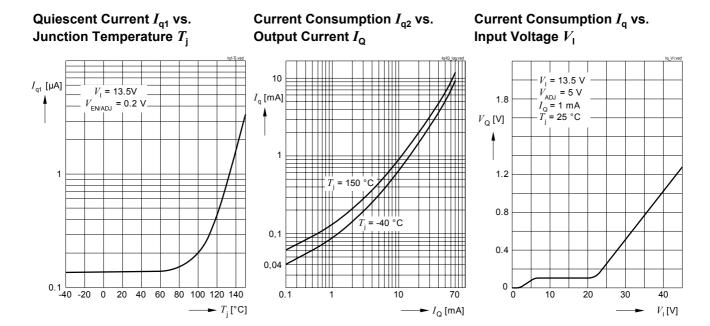
3.2 Current Consumption

Table 2 Electrical Characteristics Current Consumption

 $V_{\rm I}$ = 13.5 V; $V_{\rm ADJ/EN}$ \geq 2.0 V; $V_{\rm FB}$ = $V_{\rm Q}$ (version GA); -40 °C \leq $T_{\rm j}$ \leq 150 °C; $C_{\rm Q}$ = 1 $\mu \rm F$ all voltages with respect to ground (unless otherwise specified).

Pos.	Parameter	Symbol	Limit Values			Unit	Conditions
			Min.	Тур.	Max.		
3.2.1	Quiescent Current Stand-by Mode	I_{q1}	_	1	5	μΑ	$V_{\rm ADJ/EN} \le 0.4 \text{ V};$ $T_{\rm i} \le 125 ^{\circ}\text{C}$
3.2.2	Current Consumption $I_q = I_l - I_Q$	$I_{ extsf{q2}}$	_	50	80	μΑ	$I_{\rm Q} \le 100 \ \mu {\rm A};$ $V_{\rm ADJ/EN} = 5 \ {\rm V}$
3.2.3			_	9	15	mA	$I_{\rm Q} \le 70$ mA; $V_{\rm ADJ/EN} = 5$ V

Typical Performance Characteristics Current Consumption





3.3 Adjust / Enable Input

In order to reduce the quiescent current to a minumum, the TLE 4254 G can be switched to stand-by mode by setting the adjust/enable input "ADJ/EN" to "low".

In case the pin "ADJ/EN is left open, an internal pull-down resistors keeps the voltage at the pin low and therefore ensures that the regulator is switched off.

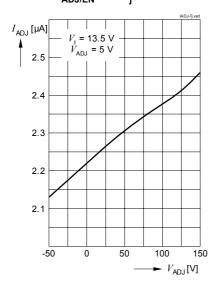
Table 3 Electrical Characteristics Adjust / Enable

 $V_{\rm I}$ = 13.5 V; $V_{\rm ADJ/EN}$ \geq 2.0 V; $V_{\rm FB}$ = $V_{\rm Q}$ (version GA); -40 °C \leq $T_{\rm j}$ \leq 150 °C; $C_{\rm Q}$ = 1 $\mu \rm F$ all voltages with respect to ground (unless otherwise specified).

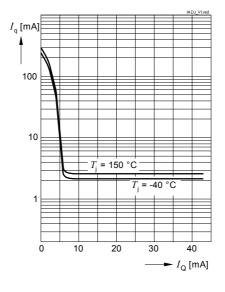
Pos.	Parameter	Symbol	L	imit Val	ues	Unit	Test Condition
			Min.	Тур.	Max.		
3.3.1	Adjust / Enable Low Signal Valid	$V_{\rm ADJ/EN,low}$	-	-	0.4	V	$V_{\rm Q}$ = 0 V; $I_{\rm Q} \le$ 5 μ A @ $T_{\rm j} \le$ 125 °C
3.3.2	Adjust / Enable High Signal Valid (Tracking Region)	$V_{ m ADJ/EN,high}$	2	-	_	V	V_{Q} settled
3.3.3	Adjust / Enable Input Current	$I_{\mathrm{ADJ/EN}}$	-	2	3	μΑ	$V_{\rm ADJ/EN}$ = 5 V
3.3.4	Adjust / Enable Input Current if Input tied to GND	$I_{ADJ/EN}$	_	0.3	0.6	mA	$V_{\text{ADJ/EN}} = 5 \text{ V};$ $V_{\text{I}} = 0 \text{ V}$
3.3.5	Adjust / Enable internal pull-down resistor	$R_{ ext{ADJ/EN}}$	1.7	2.5	3.3	ΜΩ	

Typical Performance Characteristics Adjust / Enable Input

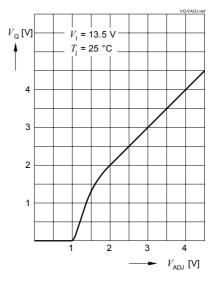
Adjust / Enable Input Current $I_{\text{ADJ/EN}}$ vs. T_{i}



Adjust / Enable Input Current $I_{\mathrm{ADJ/EN}}$ vs. V_{I}



Startup Sequence $V_{\rm Q}$ vs. $V_{\rm ADJ,EN}$





3.4 Status Output (version GS only)

The status output ST indicates an overvoltage or undervoltage situation at the regulator's output Q. Therefore, the output voltage $V_{\rm Q}$ is compared to the reference voltage $V_{\rm ADJ/EN}$. Variations of the output voltage are indicated by a low signal at the status output ST. Transients shorter than the status reaction time $t_{\rm ST,r}$ will not trigger the status output.

The status output ST is an open collector output, requiring a pull-up resisitor to a positive voltage rail.

Table 4 Electrical Characteristics Status Output ST (Version GS only)

 $V_{\rm I}$ = 13.5 V; $V_{\rm ADJ/EN}$ \geq 2.0 V; -40 °C \leq $T_{\rm j}$ \leq 150 °C; $C_{\rm Q}$ = 1 $\mu \rm F$ all voltages with respect to ground (unless otherwise specified).

Pos.	os. Parameter Symbol L		Li	mit Valu	ıes	Unit	Test Condition
			Min.	Тур.	Max.		
3.4.1	Status switching threshold, undervoltage	$V_{\scriptscriptstyle Q,UV}$	V _{ADJ/EN} - 120	<i>V</i> _{ADJ/EN} - 70	<i>V</i> _{ADJ/EN} - 50	mV	$V_{\scriptscriptstyle \mathrm{Q}}$ decreasing
3.4.2	Status switching threshold, overvoltage	$V_{Q,OV}$	V _{ADJ/EN} + 50	<i>V</i> _{ADJ/EN} + 70	V _{ADJ/EN} + 120	mV	$V_{\scriptscriptstyle m Q}$ increasing
3.4.3	Status reaction time	$t_{\rm ST,r}$	10	15	30	μs	_
3.4.4	Status output low voltage	$V_{ m ST,low}$	_	_	0.4	V	I_{ST} = 1 mA; $V_{\text{I}} \ge 4 \text{ V}$
3.4.5	Status output sink current limitation	$I_{\mathrm{ST,max}}$	1	_	_	mA	$I_{\rm ST}$ = 1 mA; $V_{\rm ST}$ = 0.8 V
3.4.6	Status output leakage current	$I_{ m ST,leak}$	_	0	2	μΑ	$V_{\rm Q} = V_{\rm ADJ/EN}$ $V_{\rm ST} = 5 \text{ V}$



Application Information

4 Application Information

Note: The following information is given as a hint for the implementation of the device only and shall not be regarded as a description or warranty of a certain functionality, condition or quality of the device.

The application circuits shown are simplified examples. The function must be verified in the real application.

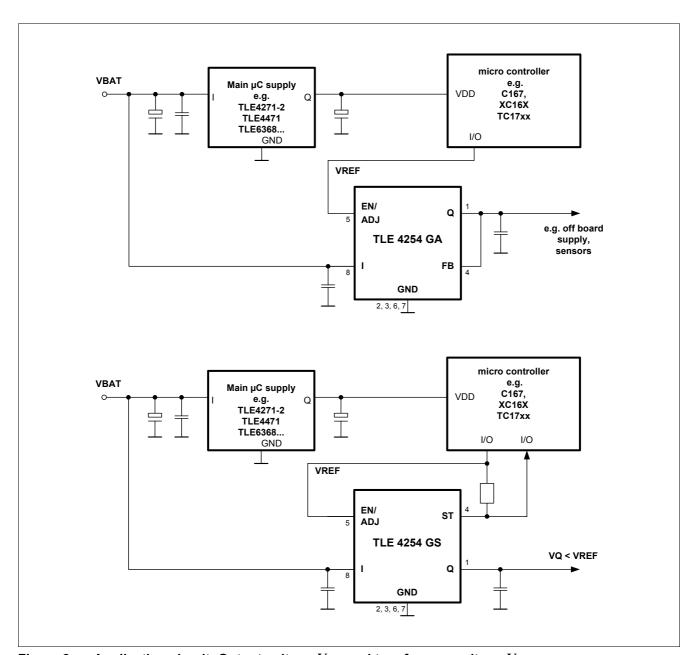


Figure 2 Application circuit: Output voltage $V_{
m Q}$ equal to reference voltage $V_{
m ADJ/EN}$

Figure 2 shows a typical schematic for applications where the tracker output voltage $V_{\rm Q}$ equals the reference voltage $V_{\rm REF}$ applied to the pin "EN/ADJ". At version GA, the pin FB is directly connected to the output "Q". The reference voltage is directly applied to "EN/ADJ".



Application Information

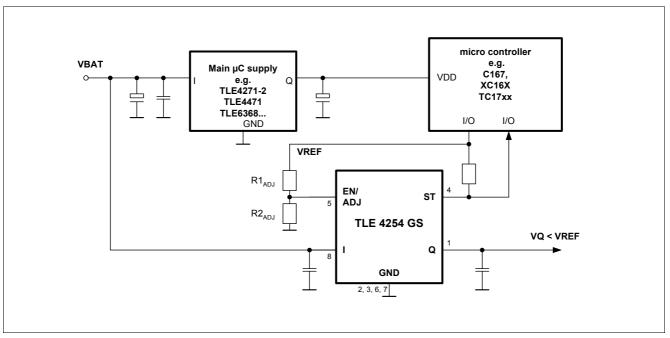


Figure 3 Application circuit: Output voltage $V_{\rm Q}$ lower than reference voltage $V_{\rm REF}$ Status Output feedbacked to microcontroller (version GS)

In order to obtain a lower output voltage $V_{\rm Q}$ at the tracker output than the reference voltage $V_{\rm REF}$, a voltage divider according to Figure 3 has to be used. The output voltage $V_{\rm Q}$ then calculates:

$$V_{Q} = V_{REF} \cdot \left(\frac{R2_{ADJ}}{R1_{ADJ} + R2_{ADJ}}\right)$$

With a given reference voltage $V_{\rm REF}$, the desired output voltage $V_{\rm Q}$ and the resistor value $RI_{\rm ADJ}$, the resistor value for $R2_{\rm ADJ}$ is given by:

$$R2_{ADJ} = R1_{ADJ} \cdot \left(\frac{V_{Q}}{V_{REF} - V_{Q}}\right)$$

Taking into consideration also the effect of the internal EN/ADJ pull-down resistor, the external resistor divider's $R2_{ADJ}$ has to be selected to:

$$R2_{ADJ,select} = \left(\frac{R2_{ADJ} \cdot R_{PullDown,min}}{R_{PullDown,min} - R2_{ADJ}}\right)$$



Application Information

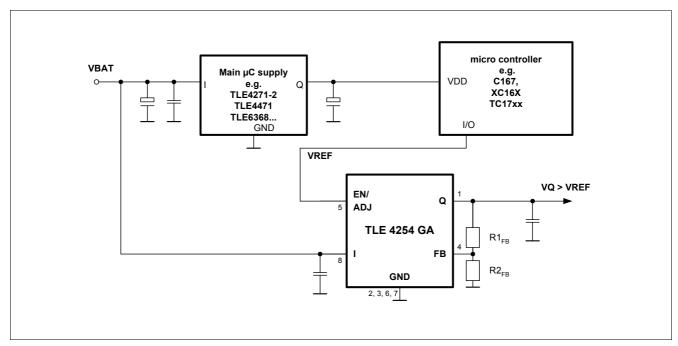


Figure 4 Application circuit: Output voltage $V_{\rm Q}$ higher than reference voltage $V_{\rm REF}$ (version GA only)

For output voltages higher than the reference voltage, the voltage divider has to be applied between the feedback and the output according to Figure 4. The equation for the output voltage with respect to the reference voltage is given by:

$$V_{Q} = V_{REF} \cdot \left(\frac{R1_{FB} + R2_{FB}}{R2_{FB}} \right)$$

Keep in mind that the input voltage has to be at minimum equal to the output voltage plus the dropout voltage of the regulator.

With a given reference voltage $V_{\rm REF}$, the desired output voltage $V_{\rm Q}$ and the resistor value $RI_{\rm FB}$, the resistor value for $R2_{\rm FB}$ is given by:

$$R2_{FB} = R1_{FB} \cdot \left(\frac{V_{REF}}{V_{O} - V_{REF}}\right)$$



Package Outlines

5 Package Outlines

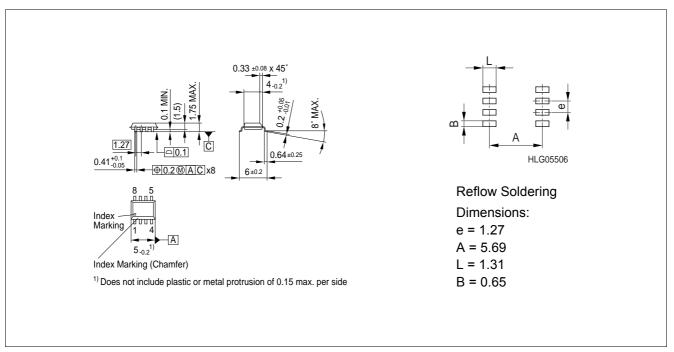


Figure 5 Outline and footprint PG-DSO-8-10

Green Product (RoHS compliant)

To meet the world-wide customer requirements for environmentally friendly products and to be compliant with government regulations the device is available as a green product. Green products are RoHS-Compliant (i.e Pb-free finish on leads and suitable for Pb-free soldering according to IPC/JEDEC J-STD-020).



Revision History

6 Revision History

TLE 4254

Revision History: 2006-11-22 Rev. 1.0

Previous Version: n/a

Edition 2006-11-22

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